# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



# Contact us

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# Obsolete



Micro Commercial Components

Micro Commercial Components 20736 Marilla Street Chatsworth CA 91311 Phone: (818) 701-4933 Fax: (818) 701-4939

#### TSMBJ0305C-072

#### **Features**

- Oxide-Glass passivated Junction
- Bi-Directional protection in a single device
- Surge capabilities up to 50A@10/1000us or 150A@8/20us
- High Off-State impedance and Low On-State voltage
- Plastic material has UL flammability classification 94V-0

#### **Mechanical Data**

- Case : Molded plastic
- Polarity : None cathode band denotes
- Approx Weight : 0.093grams

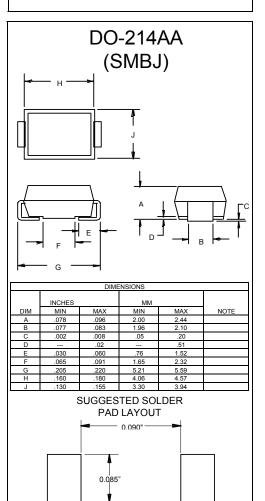
#### **Maximum Ratings**

| Characteristic                          | Symbol                            | Value     | Unit                     |
|---|-----------------------------------|-----------|--------------------------|
| Non-repetitive peak<br>impulse current  | IPP                               | 50A       | 10/1000us                |
| Non-repetitive peak<br>On-state current | I <sub>TSM</sub>                  | 20A       | 8.3ms, one-half<br>cycle |
| Operating temperature range             | T <sub>OP</sub>                   | -40~125°C |                          |
| Junction and storage temperature range  | T <sub>J</sub> , T <sub>STG</sub> | -55~150°C |                          |

#### **Thermal Resistance**

| Characteristic  | Symbol                            | Value   | Unit                      |
|---|-----------------------------------|---------|---------------------------|
| Thermal Resistance junction to lead                                     | $R_{\theta JL}$                   | 30°C/W  |                           |
| Thermal Resistance junction to ambient                                  | $R_{\theta}JA$                    | 120°C/W | On recommended pad layout |
| Typical positive<br>temperature<br>coefficient for<br>breakdown voltage | ∆V <sub>BR</sub> /∆T <sub>J</sub> | 0.1%/℃  |                           |

### Transient Voltage Protection Device 65 Volts



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0.070"

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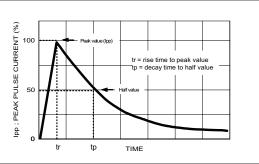
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| Parameter      | Rated<br>Repetitive Off<br>-state Voltage | Ų                | Breakover<br>Voltage | On-State<br>Voltage<br>@l <sub>T</sub> =1.0A | Breakover Current | Holding Current | Off-State<br>Capacitance |
|----------------|---|------------------|----------------------|--|-------------------|-----------------|--------------------------|
| Symbol         | V <sub>DRM</sub>                          | I <sub>DRM</sub> | V <sub>BO</sub>      | V <sub>T</sub>                               | I <sub>BO+</sub>  | I <sub>H-</sub> | CJ                       |
| Units          | Volts                                     | uA               | Volts                | Volts  | mA                | mA              | pF                       |
| Limit          | Max                                       | Max              | Max                  | Max  | Max               | Min             | Тур.                     |
| TSMBJ0305C-072 | 65  | 5                | 88                   | 5  | 800               | 150             | 100                      |

#### ELECTRICAL CHARACTERISTIC @25: Unless otherwise specified

#### MAXIMUM RATED SURGE WAVEFORM

| Waveform   | Standard      | lpp (A) |                                       |
|------------|---------------|---------|---------------------------------------|
| 2/10 us    | GR-1089-CORE  | 200     | (%)<br>L 100                          |
| 8/20 us    | IEC 61000-4-5 | 150     |                                       |
| 10/160 us  | FCC Part 68   | 100     | U U U U U U U U U U U U U U U U U U U |
| 10/700 us  | ITU-T K20/21  | 60      | PEAK PI                               |
| 10/560 us  | FCC Part 68   | 60      | dd o                                  |
| 10/1000 us | GR-1089-CORE  | 50      |                                       |



| Symbol                      | Parameter                            |                  |
|-----------------------------|--------------------------------------|------------------|
| $V_{\text{DRM}}$            | Stand-off voltage                    |                  |
| I <sub>DRM</sub>            | Leakage current at stand-off voltage |                  |
| $V_{\scriptscriptstyle BR}$ | Breakdown voltage                    |                  |
| I <sub>BR</sub>             | Breakdown current                    | I <sub>H</sub> I |
| $V_{\text{BO}}$             | Breakover voltage                    |                  |
| I <sub>BO</sub>             | Breakover current                    |                  |
| I <sub>H</sub>              | Holding current NOTE: 1              |                  |
| V <sub>T</sub>              | On state voltage                     |                  |
| I <sub>PP</sub>             | Peak pulse current                   |                  |
| Co                          | Off-state capacitance NOTE: 2        |                  |

NOTE :

1. I  $_{\rm H}$  > ( V  $_{\rm L}$ / R  $_{\rm L}$ ) If this criterion is not obeyed, the TSPD triggers but does not return correctly to high-resistance state. The surge recovery time. It does not exceed 30ms.

2. Off-state capacitance measured at f=1.0MHz , 1.0Vrms signal , VR=2Vdc bias.

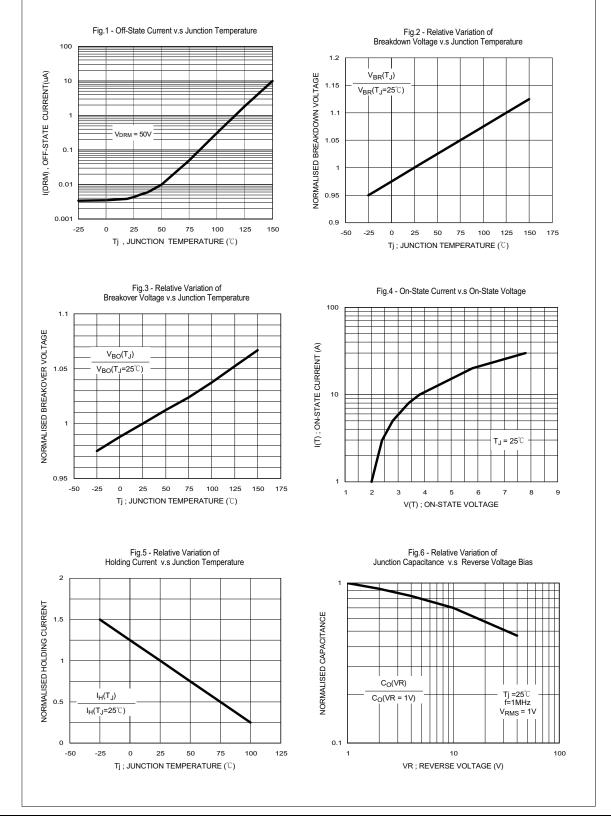
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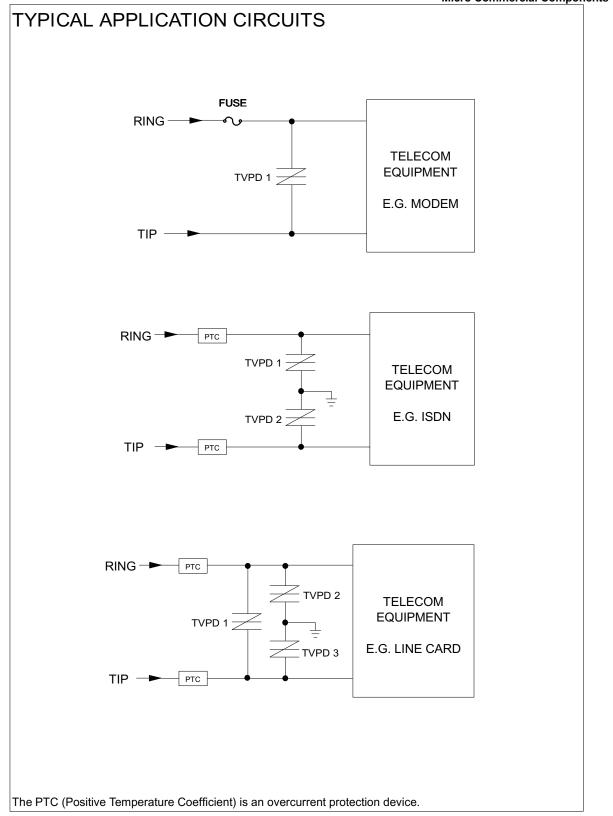


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### **MARKING CODE**



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